

Monolithic Amplifier

AVA-183A+

Mini-Circuits

50Ω 5 to 18 GHz

THE BIG DEAL

- Surface Mount Amplifier up to 18 GHz
- Integrated DC blocks, Bias-Tee & Microwave bypass capacitor
- Superior Value
- Suitable for low phase noise applications
- Gain, 13.8 dB typ. & Flatness, ±1.2 dB
- Output Power, up to +19.0 dBm typ.
- Excellent isolation, 36 dB typ. at 12 GHz
- Single Positive Supply Voltage, +5V
- Unconditionally Stable
- Aqueous washable; 3mm x 3mm SMT package



- Military EW and Radar
- DBS
- Wideband Isolation amplifier
- Microwave point-to-point radios
- Satellite systems

PRODUCT OVERVIEW

The AVA-183A+ is a surface mount, microwave amplifier fabricated using InGaAs PHEMT technology and is a fully integrated gain block up to 18 GHz. It is packaged in Mini-Circuits industry standard 3x3 mm MCLP package, which provides excellent RF and thermal performance. The AVA-183A+ integrates the entire matching network with the majority of the bias circuit inside the package, reducing the need for complicated external circuits. This approach makes the AVA-183A+ extremely flexible and enables simple, straightforward use.

KEY FEATURES

Feature	Advantages	
Wideband, 5 to 18 GHz	Broad frequency range supports a wide array of applications from microwave radio and radar , to military communica- tions and countermeasures.	
Excellent Gain Flatness	Typical ±1.2 dB gain flatness across the entire frequency range minimizes the need for external equalizer networks making it a great fit for instrumentation and EW applications.	
High Isolation	With reverse isolation of 31-42 dB (17-23 dB directivity), the AVA-183A+ is an excellent choice for buffering broadband circuits. It is an ideal LO driver amplifier and provides designers system flexibility and margin when integrating cascaded RF components.	
Single +5V Supply	No hassle associated with amplifiers using dual supply; such as power supply sequencing. Integrated output bias-tee, simplifies layout & reduces cost.	
Manufacturability	MSL1 and ESD Class1A (HBM) ratings minimize special handling on production lines.	
Low additive phase noise, typically -151 dBc/Hz @10 KHz offset	Ideal for low phase noise synthesizer applications	



Generic photo used for illustration purposes only CASE STYLE: DQ849

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our website for methodologies and qualifications





WIDEBAND, MICROWAVE Monolithic Amplifier



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ELECTRICAL SPECIFICATIONS⁽¹⁾ AT 25°C, Zo=50Ω, (REFER TO CHARACTERIZATION CIRCUIT, FIG.1)

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range		5.0		18.0	GHz
DC Voltage (V _{D1} , V _{D2})			5.0		V
DC Current (I _{D1} +I _{D2})		104	131	166	mA
/	5.0	_	12.9	_	
	8.0	12.0	14.7	_	
	10.0	12.0	14.0	_	
Gain	12.0	_	13.4	_	dB
	14.0	_	13.1	_	
	16.0	_	13.6	_	
	18.0	10.8	12.4	_	
	5.0	2010	10.4		
	8.0		17.0		
	10.0		11.0		
nput Return Loss	12.0		11.0		dB
nput Neturn 2033	14.0		11.0		40
	16.0		11.0		
	18.0		7.5		
	5.0		8.0		
	8.0		18.0		
	10.0		14.0		
					dB
Dutput Return Loss	12.0		11.0		aв
	14.0		10.6		
	16.0		11.2		
	18.0		11.8		
	5.0		32.2		
	8.0		29.0		
	10.0		27.7		
Output IP3 (2)	12.0		26.3		dBm
	14.0		25.1		
	16.0		24.3		
	18.0		24.4		
	5.0	—	17.6		
	8.0	-	18.0		
	10.0	16.0	19.0		
Dutput Power @ 1 dB compression	12.0	_	19.0		dBm
	14.0	—	19.9		
	16.0	_	19.6		
	18.0	_	18.7		
	5.0		7.4		1
	8.0		4.3		
	10.0		4.5		
Noise Figure	12.0		4.8		dB
5	14.0		5.1		
	16.0		5.1		
	18.0		6.0		
Additive Phase Noise 5.0 GHz, 10KHz offset	10.0		-151		dBc/Hz
Directivity (Isolation-Gain)	12		23.1		dB
DC Current Variation vs. Temperature (3)	12		0.046		mA/°C
Thermal Resistance			61		°C/W
			01	1	C/ VV

MAXIMUM RATINGS⁽⁴⁾

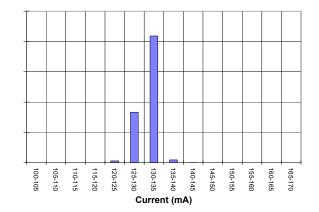
Parameter	Ratings	
Operating Temperature (5)	-40°C to 85°C	
Storage Temperature	-55°C to 100°C	
Channel Temperature	150°C	
DC Voltage (Pad 7,8)	+5.5 V	
DC Voltage (Pads 2, 5)	+10 V	
Power Dissipation	980 mW	
DC Current (Pad 7+8)	180 mA	
Input Power (CW)	+20 dBm	

(1) Measured on Mini-Circuits Characterization test fixture TB-547-2+ See Characterization Test Circuit (Fig. 1)

(2) At Pout=9dBm/tone

(2) (A rote - control at 85°C - Current at -45°C)/130
(4) Permanent damage may occur if any of these limits are exceeded. These maximum ratings are not intended for continuous normal operation.

(5) Defined with reference to ground pad temperature.



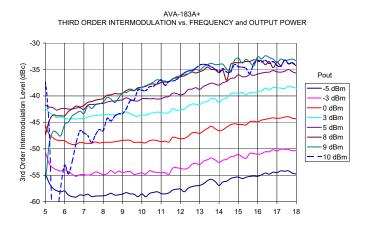
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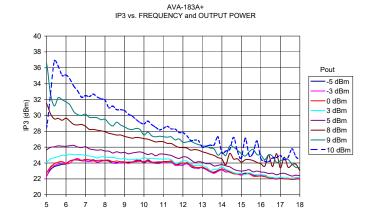


WIDEBAND, MICROWAVE Monolithic Amplifier

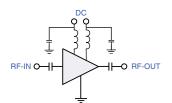
AVA-183A+

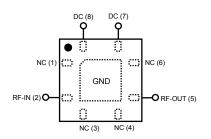
INTERMODULATION AND IP3 VS. FREQUENCY AND OUTPUT POWER





SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION





Function	Pad Number	Description (See Application Circuit, Fig. 2)
RF-IN	2	RF input pad
RF-OUT	5	RF output pad
DC	8(V _{D1}), 7(V _{D2})	DC power supply
GND	paddle in center of bottom	Connected to ground
NOT USED	1,3,4,6	No internal connection; recommended use: per PCB Layout PL-328

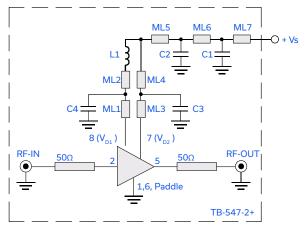


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CHARACTERIZATION TEST CIRCUIT



C1=5.6pF, 0402 (NPO) C2=18pF, 0402 (NPO) C3=0.001µF, 0402 (NPO) C4=0.1 µF, 0402 (X7R) L1=3.3nH, 0805 (wire wound) ML1-ML7 are short microstrip lines Refer to 98-PL-328 Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-547-2+) Gain, Output power at 1dB compression (P1dB), Noise Figure, Output IP3 (OIP3) are measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

- 1. Gain: Pin=-25 dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 9 dBm/tone at output.
- 3. Vs adjusted for 5.0V at device (VD1 and VD2), compensating loss of bias lines.

RECOMMENDED APPLICATION CIRCUIT

(refer to evaluation board for PCB Layout and component values)

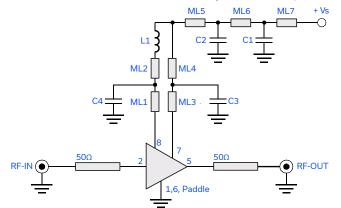
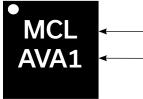


Fig 2. Recommended Application Circuit

C1=5.6pF, 0402 (NPO) C2=18pF, 0402 (NPO) C3=0.001µF, 0402 (NPO) C4=0.1 µF, 0402 (X7R) L1=3.3nH, 0805 (wire wound) ML1-ML7 are short microstrip lines Refer to 98-PL-328

PRODUCT MARKING



black body

model family designation

Marking may contain other features or characters for internal lot control



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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

Performance Data	Data Table Swept Graphs S-Parameter (S2P Files) Data Set (.zip file)
Case Style	DQ849 Plastic package, exposed paddle, lead finish: Matte-tin
Tape & Reel Standard quantities available on reel	F104 7" reels with 20, 50, 100, 200, 500, 1000 or 2000 devices
Suggested Layout for PCB Design	PL-328
Evaluation Board	TB-547-2+
Environmental Ratings	ENV08T1

ESD RATING

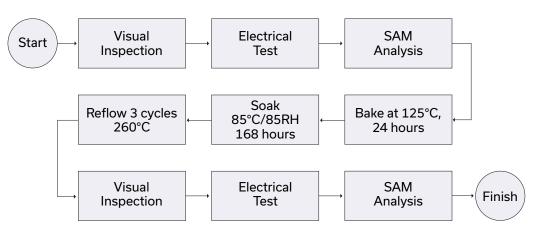
Human Body Model (HBM): 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): M1 (25V) in accordance with ANSI/ESD STM5.2-1999

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

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